

# MA INTENANCE MANUAL 406—512 MHz OSCILLATOR/MULTIPLIER BOARD 19D423266GI-GIO

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#### DESCRIPTION

The MASTR® II oscillator-multiplier (Osc/Mult) can be equipped with up to eight Integrated Circuit Oscillator Modules (ICOMS). The ICOM crystal frequencies range from approximately 14.5 to 18.5 megahertz, and the crystal frequency is multiplied 27 times and then amplified to provide a low side in injection frequency to the mixer. Optional ICOMs are available for high side injection.

In receivers equipped with a Dual Front End (DFE), a second Osc/Mult board is used. A total of eight ICOMs can be used between the two Osc/Mult boards.

#### CIRCUIT ANALYSIS

ICOMs

Three different types of ICOMs are available for use in the Osc/Mult module. Each contains a crystal-controlled Colpitts oscillator, and two of the ICOMs contain compensator ICs. The different ICOMs are:

- 5C-ICOM contains an oscillator and a 5 part-per-million (±0.0005%) compensator IC. Provides compensation for EC-ICOMs.
- EC-ICOM contains an oscillator only. Requires external compensation from a 5C-ICOM.
- 2C ICOM contains an oscillator and a 2 PPM (±0.0002%) compensator IC. Will not provide compensation for an EC-ICOM.

The ICOMs are enclosed in an RF shielded can with the type ICOM (5C-ICOM, EC-ICOM or 2C-ICOM) printed on the top of the can. Access to the oscillator trimmer is obtained

through a hole on top of the can.

Frequency selection is accomplished by switching the ICOM keying lead (terminal 6) to A- by using the frequency selector switch on the control unit. In single frequency radios, a jumper from H9 to H10 in the control unit connects terminal 6 of the ICOM to A-.

In DFE applications, keying leads of the receiver and the DFE Osc/Mult ICOMs are operated in parallel. Therefore, ICOMs in the receiver can not be placed in the same position as those in the DFE.

In the receive mode, +10 Volts is applied to the external ICOM load resistor (R401) by the RX Osc control line, keeping the selected ICOM turned on. Keying the transmitter removes the 10 Volts at R401, turning the ICOM off.

--CAUTION-

All ICOMs are individually compensated at the factory and cannot be repaired in the field. Any attempt to repair or change an ICOM frequency will void the warranty.

In standard 5 PPM radios using EC-ICOMs, at least one 5C-ICOM must be used. The 5C-ICOM is normally used in the receiver F1 position, but can be used in any transmit or receive position. One 5C-ICOM can provide compensation for up to 15 EC-ICOMs in the transmitter and receiver. Should the 5C-ICOM compensator fail in the open mode, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (+32°F to 131°F) due to the regulated compensation voltage (+5 Volts) from the 10-Volt regulator IC. If desired, up to 16 5C-ICOMs may be used in the radio.

The 2C-ICOMs are self-compensated to 2 PPM and can not provide compensation for EC-ICOMs.

When a DFE is used with a wide spaced transmitter option, compensation voltage for the 5C-ICOMs is supplied from the EC-ICOM. Should the 5C-ICOM fail, the EC-ICOMs will still maintain 2 PPM frequency stability from 0°C to 55°C (32°F to 131°F) due to the regulated compensation voltage.

#### Oscillator Circuit

The quartz crystals used in ICOMs exhibit the traditional "S" curve characteristics of output frequency versus operating temperature.

At both the coldest and the hottest temperatures, the frequency increases with increasing temperature. In the middle temperature range (approximately 0°C to +55°C), frequency decreases with increasing temperature. In the middle temperature range (approximately 0°C to +55°C), frequency decreases with increasing temperature.

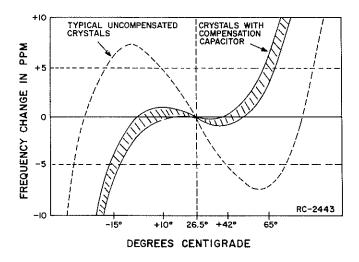


Figure 1 - Typical Crystal Characteristics

Since the rate of change is nearly linear over the mid-temperature range the output frequency change can be compensated by choosing a parallel compensation capacitor with a temperature coefficient approximately equal and opposite that of the crystal.

Figure 1 shows the typical performance of an uncompensated crystal as well as the typical performance of a crystal which has been matched with a properly chosen compensation capacitor.

At temperatures above and below the mid-range, additional compensation must be introduced. An externally generated compensation voltage is applied to a varactor (voltage-variable capacitor) which is parallel with the crystal.

A constant bias of 5 Volts (provided from Regulator IC U901 in parallel with the compensator) establishes the varactor capacity at a constant value over the entire mid-temperature range. With no additional compensation, all of the oscillators will provide 2 PPM frequency stability from 0°C to  $55^{\circ}$ C (+30°F to  $131^{\circ}$ F).

#### Compensator Circuits

Both the 5C-ICOMs and 2C-ICOMs are temperature compensated at both ends of the temperature range to provide instant frequency compensation. An equivalent ICOM circuit is shown in Figure 2.

The cold end compensation circuit does not operate at temperatures above  $0^{\circ}C$ . When the temperature drops below  $0^{\circ}C$ , the circuit is activated. As the temperature decreases, the equivalent resistance decreases and the compensation voltage increases.

The increase in compensation voltage decreases the capacity of the varactor in the oscillator, increasing the output frequency of the ICOM.

The hot end compensation circuit does not operate at temperatures below +55°C. When the temperature rises above +55°C, the circuit is activated. As the temperature increases, the equivalent resistance decreases and the compensation voltage decreases. The decrease in compensation voltage increases the capacity of the varactor, decreasing the output frequency of the ICOM.

<u>Service Note:</u> Proper ICOM operation is dependent on the closely-controlled input voltages from the 10-Volt regulator. Should all of the ICOMs shift off frequency, check the 10-Volt regulator module.

#### MULTIPLIERS & AMPLIFIER

The output of the selected ICOM is coupled through a tuned circuit (L401 and C406) that is tuned to three times the crystal frequency. The output of the tuned circuit is applied to the base of Class C multiplier Q401. The collector tank circuit of the multiplier (L402, C411 and C412) is tuned to nine times the crystal frequency. The output of the multiplier stage is metered through a metering network consisting of C427 and L405, and applied to receiver metering jack J601 through P903-14.

Following the multiplier is a Class A Amplifier stage, Q402. The output of Q402 is metered through a metering network consisting of C419, C420, CR402 and R408 and applied to receiver metering jack J601 through P903-15. The amplified output of Q402 is applied to a tuned circuit (L403, C416 and C417) that is tuned to nine times the crystal frequency. The tuned circuit provides some selectivity in the oscillator-multiplier chain.

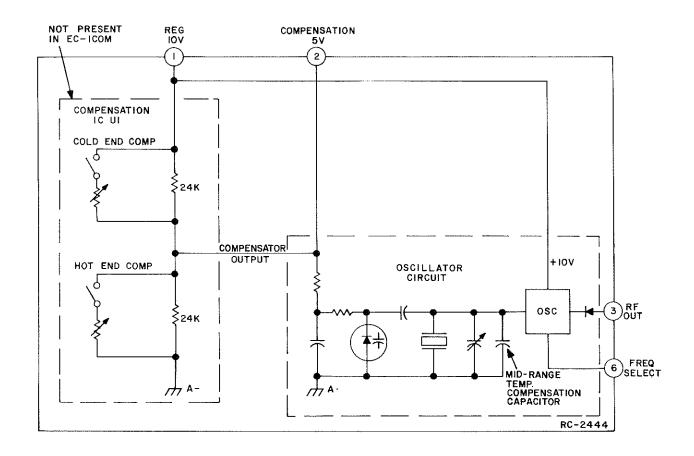


Figure 2 - Equivalent ICOM Circuit

The amplifier output is applied to the base of Class C multiplier Q403 through a matching network (T401 and C426). The output of Q403 is inductively coupled to the first of three helical resonators on the RF Assembly through L407. The helicals are tuned to 27 times the crystal frequency.

Most of the selectivity for the oscillator-multiplier chain is provided by the three high-Q helicals. The output of the

helicals is applied to the input of the mixer stage on the RF Amplifier assembly.

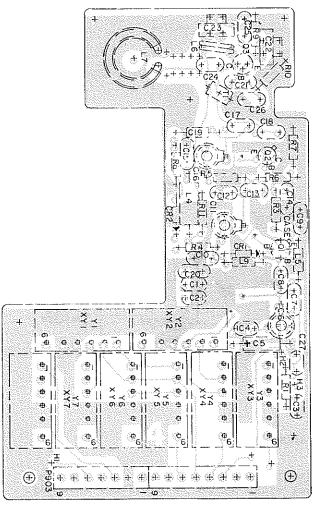
The multiplier output is metered at J605-7 through a metering network on the IF-Filter board. The metering network consists of L505, L506, C512, C513, C514, CR501 and R506.

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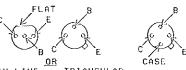
### OSC/MULT BD

#### SOLDER SIDE



(19D423267, Sh. 2, Rev. 4)

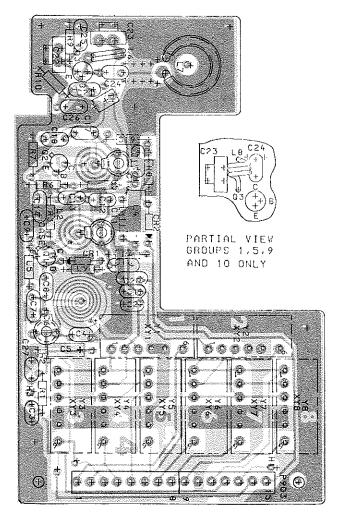
LEAD IDENTIFICATION
FOR Q2 AND Q3 FOR Q1



IN-LINE TRIANGULAR TOP VIEW

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

#### COMPONENT SIDE



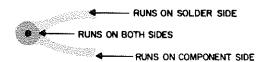
(19D423267, Sh. 2, Rev. 4) (19D423267, Sh. 3, Rev. 4)

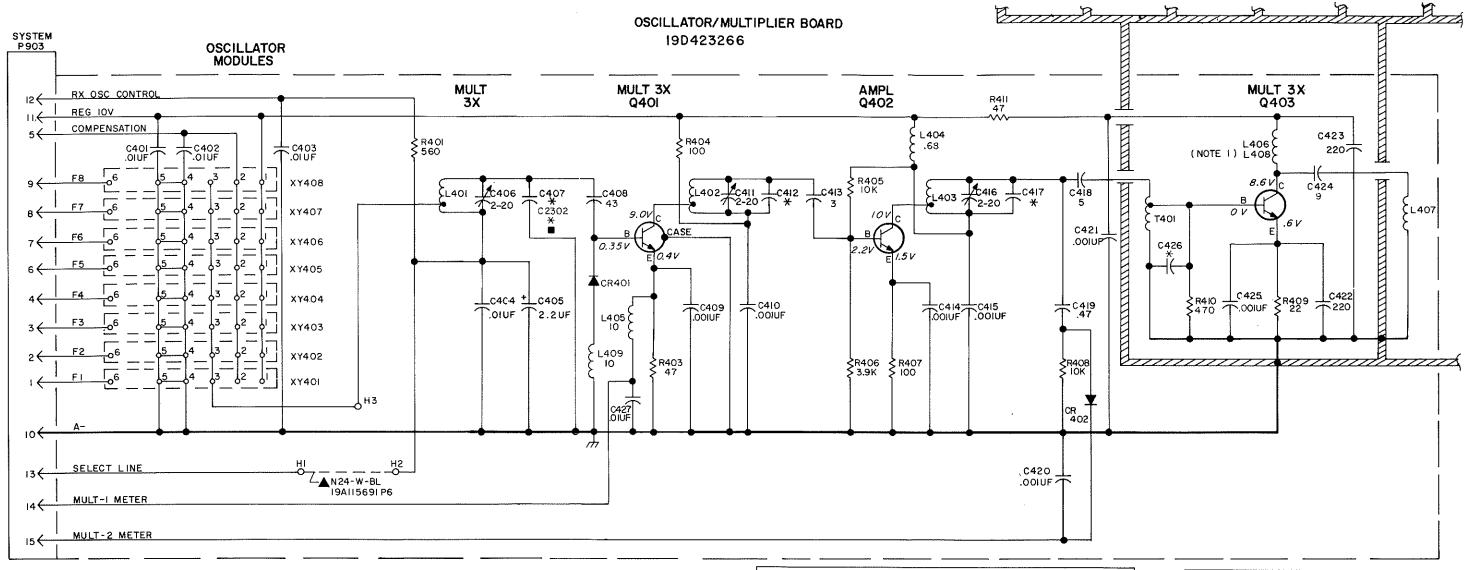
NOTE
PARTIAL REFERENCE DESIGNATIONS ARE
SHOWN, FOR COMPLETE DESIGNATIONS,
PREFIX VITH 400 SERIES.
EXAMPLE: C1-C401, R1-R401, ETC...

(19D423790, Rev. 6)

# **OUTLINE DIAGRAM**

406-512 MHz OSCILLATOR/MULTIPLIER BOARD 19D423266G1-G8





NOTE: 1. L406 - G2, G3, G4, G6, G7, & G8 L408 - G1, G5, G9 & G10

* COMPONENT VALUE TABLE					
COMP. DESIGN	LL	L	М	Н	I M
RF FREQ (MHz)	406-420	450-470	470-494	494-512	420-450
C407	24	18	12	13	18
C412	12	5	5	4	8
Ç417	6	3		-	3
C 426	12	8	6	6	10
C2302	18	3			10

IN ORDER TO RETAIN RATED EQUIPMENT PERFORMANCE, REPLACEMENT OF ANY SERVICE PART SHOULD BE MADE ONLY WITH A COMPONENT HAVING THE SPECIFICATIONS SHOWN ON THE PARTS LIST FOR THAT PART.

ALL RESISTORS ARE 1/4 WATT UNLESS OTHERWISE SPECIFIED AND RESISTOR VALUES IN OHMS UNLESS FOLLOWED BY K=1000 OHMS OR MEG = 1,000,000 OHMS OCAPACITOR VALUES IN PICOFARADS (EQUAL TO MICROMICROFARADS) UNLESS FOLLOWED BY UF = MICROFARADS, INDUCTANCE VALUES IN MICROHENRYS UNLESS FOLLOWED BY MH= MILLIHENRYS OR H= HENRYS.

AS AND WITH A DUAL FRONT END. T IGNORED IN THE STANDARD RECEIVER	APT A STANDARD MASTR II RECEIVER TO OPERATION THESE COMPONENTS SHOULD BE R. BOARDS IDENTIFIED BY A RED DOT ATION PER MOD KIT 19A129750GI OR G2
RECEIVER CHANNEL	D.F.E. CHANNEL
SEE IF FILTER BD FOR OTHER DFE CHANGES	NO MODIFICATION REQUIRED ON THE IF FILTER BD
ON PL19D417072 (OSC/MULT BD) NO MODIFICATION REQUIRED	ON PL19D417072 (OSC/MULT BD)  1. N24-W-BL JUMPER ADDED BETWEEN H1 & H2 ON OSC/MULT BD.
THESE ITEMS ARE SUPPLIED IN MOD. KIT PLI9AI2975061.	THESE ITEMS ARE SUPPLIED IN MOD. KIT PLIGATESTOGE.

THESE COMPONENTS USED TO ADAPT A STANDARD RECEIV	ER TO	9-12	FREQ.	OPERA!!
OSC/MULT BD> 190423266 1. C2302LL IS USED INSTEAD OF C407LL 2. C2302L IS USED INSTEAD OF C407LL 3. C2302LM IS USED INSTEAD OF C407LM THESE ITEMS ARE SUPPLIED IN KIT PLIPAL 2973762. (MOD DRAMING 190417218)				

	REV LETTER	FREQ RANGE (MHZ)	NO. OF FREQ
OSC/MULT BD			
19D423266G1	К	406-420	2
19D423266G2	J	450-470	2
19D423266G3	К	470-494	2
19D423266G4	Н	494-512	2
19D423266G5	К	406 - 420	8
19D423266G6	J	450-470	8
19D423266G7	К	470-494	8
19D423266G8	н	494-512	8
19D423266G9	G	420-450	2
19D423266GIO	G	420-450	8

## SCHEMATIC DIAGRAM

406—512 MHz OSCILLATOR/MULTIPLIER BOARD 19D423266G1-G8

#### **PARTS LIST**

LB130030G

406-512 MHz OSCILLATOR/MULTIPLIER 19D423266G1-G10

SYMBOL	GE PART NO.	DESCRIPTION
		19D423266G1 2 FREQ 406-420 MHz (LL) REV K 19D423266G2 2 FREQ 470-470 MHz (L) REV K 19D423266G3 2 FREQ 470-494 MHz (M) REV K 19D423266G4 2 FREQ 494-512 MHz (L) REV H 19D423266G6 8 FREQ 406-12 MHz (L) REV K 19D423266G6 8 FREQ 450-470 MHz (L) REV J 19D423266G6 8 FREQ 470-494 MHz (M) REV K 19D423266G8 8 FREQ 470-494 MHz (M) REV K 19D423266G9 2 FREQ 494-512 MHz (H) REV H 19D423266G9 2 FREQ 420-450 MHz (LM) REV G
C401 thru C404	19A700234P7	Polyester: 0.01 µf ±10%, 50 VDCW.
C405	5496267P13	Tantalum: 2.2 $\mu$ f $\pm 20\%$ , 20 VDCW; sim to Sprague Type 150D.
C406	19A700012P2	Variable, ceramic: 2.5 to 20 pf, 200 VDCW, temp coef -250 -700 PPM/°C; sim to Panasonic ECV-1ZW20X32.
C407LL	19A143491P24J8	Ceramic disc; 24 pf ±5%, 500 VDCW, temp coef -80 PPM.
C407L	19A143491P18J8	Ceramic disc: 18 pf ±5%, 500 VDCw, temp coef -80 PPM.
C407M	19A143491P12J0	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef -80 PPM.
C4 07H	19A143491P13J8	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
C408*	19A116656P43J0	Ceramic disc: 43 pf ±5%, 500 VDCm, temp coef O PPM. In Gl & G5 of REV C & earlier;
		In G2-G4, G6-G8 of REV B & earlier:
	19All6656₽15J0	Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef 0 PPM.
C4 09 and C4 10	19A143481P19	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C411	19A700012P1	Variable, ceramic; 2 to 10 pf, 200 VDCW, temp coef -350 +500 PPM/°C; sim to Panasonic ECV- 1ZW10X32.
C4 12LL*	19A143491P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coof 0 PPM.
		In REV D & earlier:
	19A116656P10J0	Ceramic disc: 10 pf ±0.5 pf, 500 VDCw, temp coe: 0 PPM.
C412L	19A143491P6G0	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coe. 0 PPM.
C412LM	19A143491P8J0	Ceramic disc: 8 pf ±0.25 pf, 500 VDCW, temp coe. 0 PPM.
C412M	19A143491P5G0	Ceramic disc: 5 pf ±0.25 pf, 500 VDCW, temp coe 0 PPM.
C4 12H	19A143491P4G0	Ceramic disc: 4 pf ±0.25 pf, 500 VDC%, temp coe 0 PPM.
C413	19A143491P3K0	Ceramic disc: 3 pf ±1 pf, 500 VDCW, temp coef 0 PPM.
C414 and C415	19A143481P19	Ceramic disc: 1000 pf ±20%, 1000 VDC%; sim to RMC Type JF Discap.
C416	19A700012P1	Variable, ceramic: 2 to 10 pf, 200 VDCH, temp coef ~350 +500 PPM/°C; sim to Panasonie ECV-1ZW10X32.
C417LL*	19A143491P6G0	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coe 0 PPM.
	19A116656P4G0	In REV D & earlier;  Ceramic disc: 4 pf ±0.25 pf, 500 VDCW, temp coe 0 PPM.

SYMBOL	GE PART NO.	DESCRIPTION	
C417L	19A143491P3G0	Ceramic disc: 3 pf ±0.25 pf, 500 VDCm, temp coel	
C418	19A1±3491P5J0	O PPM.  Ceramic disc: 5 pf ±0.5 pf, 500 VDCh, temp coef	
C4 19	5491601P13	O PPM,	
C420 and C421	19A143481P19	Phenolic: 0.47 pf ±10%, 500 VDCW.  Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
C422 and C423	19A116679P220K	Mica: 220 pf ±10%, 250 VDCW.	
C424*	19A143491P9JO	Ceramic disc: 9 pf ±0.5 pf, 500 VDCm, temp coef 0 PPM.	
		In G1 & G5 REV F; In G2, G3, G6 & G7 REV E; In G4 & G8 REV D; In G9 & G10 REV C;	
	198116356P7J0	Ceramic disc: 7 pf ±0.5 pf, 500 VDCh, temp coef 0 PPM. Added to G1 & G5 by REV F. Added to G2, G3, G6, G7 by REV E. Added to G9 & G10 by REV C.	
C424LL*	19А116656Р9КО	Ceramic disc: 9 pf ±1 pf, 500 VDCW, temp coef 0 PPM. Added to Gl & G5 by REV E. Deleted in Gl & G5 by REV F.	
C424L*	19A116356P9K0	Ceramic disc: 9 pf ±1 pf, 500 VDCW, temp coef 0 PPM. Added to G2 & G6 by REV D. Deleted in G2 & G6 by REV K.	
C4241.M*	19A116356P9KO	Ceramic disc: 9 pf ±1 pf, 500 VDCW, temp coef 0 PPM. Added to 69 & G10 by REV B. Deleted in G9 & G10 by REV C.	
C424M*	19А116656Р9КО	Ceramic disc: 9 pf $\pm 1$ pf, 500 VDCW, temp coef 0 PPM. Added to G3 & G7 by REV D. Deleted in G3 & G7 by REV E.	
C424H*	19A116656P7J0	Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM, Added to G4 & G8 by REV D.	١
C424*	19A116656P9KO	Ceramic disc: 9 pf ±1 pf, 500 VDCN, temp coef 0 PPM. Deleted by REV E in Gl & G5. Deleted by REV D in G2-G4, G5-G8. Deleted by REV B in G9, G10.	
C425*	19A143481P19	Ceramic disc; 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
	19A116080P101	Polyester: 0.01 µf ±10%, 50 VDCM. In REV C & earlier:	
	19A116655P19	Ceramic disc; 1000 pf ±20%, 1000 VDCh; sim to RMC Type JF Discap.	1
C426	19A116656P3KO	Ceramic disc: 3 pf ±1 pf, 500 VDCW, temp coef 0 PPM.	
C42611	19A143491P12J0	Ceramic disc: 12 pf ±5%, 500 VDCW, temp coef 0 PPM.	
C426LM	19A143491P10J0	Ceramic disc: 10 pf ±0.5 pf, 500 VDCw, temp coef 0 PPM.	
C426L	19A143491P8J0	Ceramic disc: 8 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	
C426M	19A143491P6J0	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	
C426H	19A143491P6J0	Ceramic disc: 6 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	
C427	19A700234P7	Polyester: 0.01 µf ±10%, 50 VDCW.	
		DIODES AND RECTIFIERS	
CR402	19A116052P5	Silicon, capacitive.	
LA01 thru LA03			
LA 06+	19A129711P1	Coil. Deleted in Gl, G5 by REV A.	
LA 07	19A129710P1	Coil.	
LA 08*	19A129352P8	Coll. Added to Gl, G5 by REV A.	

	SYMBOL	GE PART NO.	DESCRIPTION
Ì			PLUGS
	P903		Includes:
1		19B219594P1	Terminal strip: 7 pins.
		19B219594P2	Terminal strip: 8 pins.
-	Q401*	19A134447Pl	Silicon, NPN; sim to Type 2N5179.
			In G1, G5 of REV A $\alpha$ earlier; in G2-G4, G6-G8 earlier than REV A:
1		19A115440P1	Silicon, NPN.
	Q402	19A116899P1	Silicon, NPN; sim to Type 2N2368.
	Q403	19A11620LP1	Silicon, NPN.
			TRANSFORMERS
	T401	19A127108G3	Coil.
	v114.03	10470178501	Contact, electrical; sim to Molox 08-50-0404.
	XY401 thru XY408	19A701785Pl	(Quantity 6 for each socket).
	X1400		
			ASSOCIATED ASSEMBLIES
			NOTE: When reordering specify ICOM Frequency.
			FOR STANDARD LOW SIDE INJECTION FREQUENCY
			ICOM Freq = Operating Freq - 11.2
	Y401	19A12939G12	Compensated: ±5 PPM, 406-420 MHz, 450-512 MHz.
	thru Y408		
		19A129393G8	Externally Compensated: ±5 PPN, 406-420 MHz, 450-512 MHz.
		19A12939364	Compensated: ±2 PPM, 406-420 MHz, 450-512 MHz.
			•
			NOTE: FOR HIGH SIDE INJECTION FREQUENCY
			ICOM Freq = Operating Freq + 11.2 27
	Y401 thru	19A130283G6	Compensated: ±5 PPM. 406-420 MHz, 450-512 MHz.
	Y408	19A130283G4	Externally Compensated: ±5 PPM, 406-512 MHz.
		19A130283G2	Compensated: ±2 PPM, 406-512 MHz.
			DUPLEX HIGH SIDE INJECTION KIT
			19A130045G5
	C2315	19A116656P13J8	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -80 PPM.
	C2316	19A116656P5J0	Ceramic disc: 5 pf ±0.5 pf, 500 VDC%, temp coef
	C2317	19A116656P8J8	O PPM. Ceramic disc: 8 pf ±0.5 pf, 500 VDCW, temp coef
	U2311	LANTIUGUGFOVO	-80 PPM.
	C2318	19A116d56P10J8	Ceramic disc: 10 pf ±5%, 500 VDCW, temp coef -80 PPM.
	C2319	19A116656P4J0	Ceramic disc: 4 pf ±0.5 pf, 500 VDCw, temp coef 0 PPM.
	C2320	19A116656PGJ8	Ceramic disc: 6 pf ±0.5 pf, 500 VDCW, temp coef -80 PPM.
	C2321	19A116356P3J0	Ceramic disc: 3 pf ±0.5 pf, 500 VDCW, temp coef
			O PPM.
		1	
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SYMBOL	GE PART NO.	DESCRIPTION
		9-12 FREQ. MOD KIT 19A129737G2
C2301H	19A116656P7K1	Ceramic disc: 7 pf ±1 pf, 500 VDCW, temp coef -150 PPM.
C2301L	19A116356P10K1	Ceramic disc: 10 pf $\pm 1$ pf, 500 VDCW, temp coef -150 PPM.
C2302LL	19A116356P18J8	Ceramic disc: 18 pf $\pm 5\%$ , 500 VDCW, temp coef $-80$ PPM.
C5305F	19A116656P3J8	Ceramic disc: 3 pf $\pm 0.5$ pf, 500 VDC%, temp coe-80 PPM.
C2302LM	19A116656P10J8	Ceramic disc: 10 pf ±0.5 pf, 500 VDCW, temp co- -80 PPM.
	4031594P1	Insulator. (Located under C406, C411, C416).
	19A701332P1	Insulator: sim to Thermalloy 7717-46. (Used with $\mathbf{Q403}$ ).

#### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - 19D423266G1 & G5

To improve operation of oscillator/multiplier in 406-420 MHz band. Deleted coil L406 and added coil L408.

REV. B - 19D423266G1 & G5

REV. A - 19D423266G2-G4 & G6-G8

To provide uniform output over multi-frequency range. Changed Q401.

REV, B - 19D423266G2-G4 & G6-G8

REV. C - 19D423266G1 & G5

To increase output of OSC/MULT board with multiple ICOMs. Added L409.

REV. D - 190423266G1 & G5

REV. C - 190423266G2-G4 & G6-G8

To improve drive to first Multiplier. Changed C408.

REV. E - 19D423266G1, G5

REV. D - 19D423266G2, 3, 4, 6, 7, 8

REV. A ~ 19D423266G9, G10

To allow operation in 420-450 MHz range. Deleted L406. Added L408.

REV. B - 19D423266G9, G10

To improve tuning. Changed C412, C417 and C425 in Groups 1 and 5. Changed C425 in Groups 2, 3, 6, 7, 9 and 10.

REV. F - 19D423266G1 & G5

REV. E - 19D423266G2, G3, G6, G7

REV. C - 19042326669 & G10

To improve operation. Deleted C424LL, C424L, C424LM, C424M and C424H. Added C424 (19All6656P7JO) for Groups 1 thru 10.

REV. G - 19D423266G1 & G5

REV. F - 19D423266G2, G3, G6 & G7

REV. E - 19D423266G4 & G8

REV, D - 19D423266G9 & G10 To improve operation of multiplier operation. Changed C424, C425 and R410.

REV. H - 19D423266G1 & G5

REV G - 19D423266G2, G3, G6 & G7

REV. F - 19D423266G4 & G8

REV, E - 19D42326669 & G10

To incorporate new transistor. Changed Q402.

REV. J - 190423266G1 & G5 REV. H - 190423266G2, G3, G6 & G7 REV. G - 190423266G4 & G8 REV. F - 180423266G9 & G10

To increase the injection level to provide better sensitivity.

Deleted C426, added C426LL, C426LM, C426L, C426M and C426H.

Changed R410 and T401. Components were: C426 - 19A116656P3KO,

Ceramic disc; 3 pf ±1 pf, 500 VDCW, temp coef OPPM, R410 19A700106P39, composition; 100 ohms ±5%, 1/4 W. T401 - 19A129920G1;

Coil coil.

REV. K - 19D423266G1, G3 & G7 REV. J - 19D423266G2 & G6 REV. H - 19D423266G4, G5 & G8 REV. G - 19D423266G9 & G10

To prevent the receiver from self-quieting, caused by IF getting into the oscillator-multiplier on the 10 Volt line. Changed C401. C401 was: 19A116655P19 - Ceramic disc; 1000 pf ±20%, 1000 VDCW; sim to RMC type JF Discap.

<sup>\*</sup>COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES.